Unitized Semiconductor Devices - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

0.450 inches

### **Overall Width:**

1.050 inches

#### **Mounting Facility Quantity:**

### 2

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Cathode

#### **Component Name And Quantity:**

### 2 semiconductor device diode

**Mounting Method:** 

Unthreaded hole

### **Features Provided:**

Hermetically sealed case and electrostatic sensitive

### Semiconductor Material:

Silicon all semiconductor device diode

# Voltage Rating In Volts Per Characteristic:

54.0 nonrepetitive peak reverse voltage all semiconductor device diode and 45.0 working peak reverse voltage all semiconductor device diode

## **Current Rating Per Characteristic:**

30.00 amperes forward current, average absolute all semiconductor device diode and 500.00 amperes forward current, average preset all semiconductor device diode

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

#### Test Data Document:

96214-807880 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

2 pin and 1 case

#### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

No

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